NSN 5961-01-216-5319

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-216-5319 **Inclosure Material:** Plastic **Overall Length:** 5.2 millimeters **Terminal Length:** 12.7 millimeters **Overall Height:** 1.2 millimeters **Overall Width:** 5.2 millimeters **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 19.0 collector to emitter voltage/static/base open and 2.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current and -50.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**